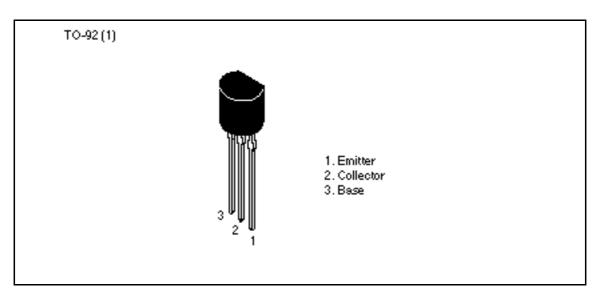
Silicon PNP Epitaxial

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Application

- Low frequency low noise amplifier
- Complementary pair with 2SC1775/A

Outline





Absolute Maximum Ratings (Ta = 25° C)

Item	Symbol	2SA872	2SA872A	Unit
Collector to base voltage	V _{CBO}	-90	-120	V
Collector to emitter voltage	V _{CEO}	-90	-120	V
Emitter to base voltage	V _{EBO}	-5	-5	V
Collector current	I _c	-50	-50	mA
Collector power dissipation	P _c	300	300	mW
Junction temperature	Тј	150	150	°C
Storage temperature	Tstg	–55 to +150	–50 to +150	°C

Electrical Characteristics (Ta = 25° C)

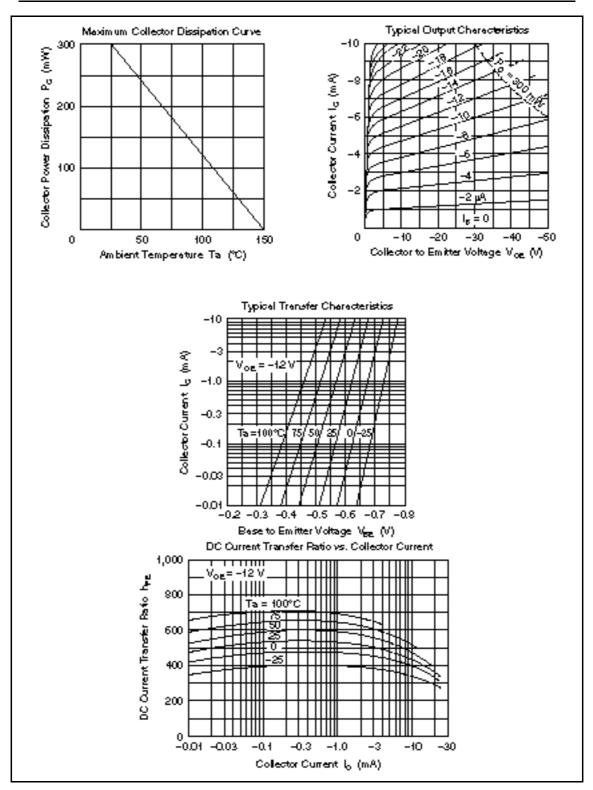
	Symbol	2SA872		2SA872A					
Item		Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{\rm (BR)CEO}$	-90	_	_	-120	_	_	V	$I_c = -1 \text{ mA}, \text{ R}_{\text{BE}} =$
Collector cutoff current	I _{CBO}	—	—	-0.5	—			μA	$V_{\rm CB} = -75 \ V, \ I_{\rm E} = 0$
		_	—	_		_	-0.5	μA	$V_{ce} = -100 \text{ V}, I_{e} = 0$
DC current tarnsfer ratio	$h_{\rm FE1}^{*1}$	250	_	800	250	_	800		$V_{ce} = -12 \text{ V},$ $I_c = -2 \text{ mA}$
	h_{FE2}	160	_	_	160	_	_		$V_{ce} = -12 \text{ V},$ $I_c = -0.1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	_	-0.75	_	_	-0.75	V	$V_{ce} = -12 V,$ $I_c = -2 mA$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	_	-0.5	_	_	-0.5	V	$I_{c} = -10 \text{ mA},$ $I_{B} = -1 \text{ mA}$
Gain bandwidth product	f _T	_	120	_	_	120	_	MHz	$V_{ce} = -12 V,$ $I_{c} = -2 mA$
Collector output capacitance	Cob	_	1.8	_	_	1.8	_	pF	$V_{CB} = -25 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz
Noise figure	NF	_	_	5.0			5.0	dB	$V_{CE} = -6 V, f = 10 H$ $I_{C} = -50 \mu A$ $R_{g} = 50 k$
		_	—	1.5	_	_	1.5	dB	f = 1 kH

Note: 1. The 2SA872/A is grouped by h_{FE1} as follows.

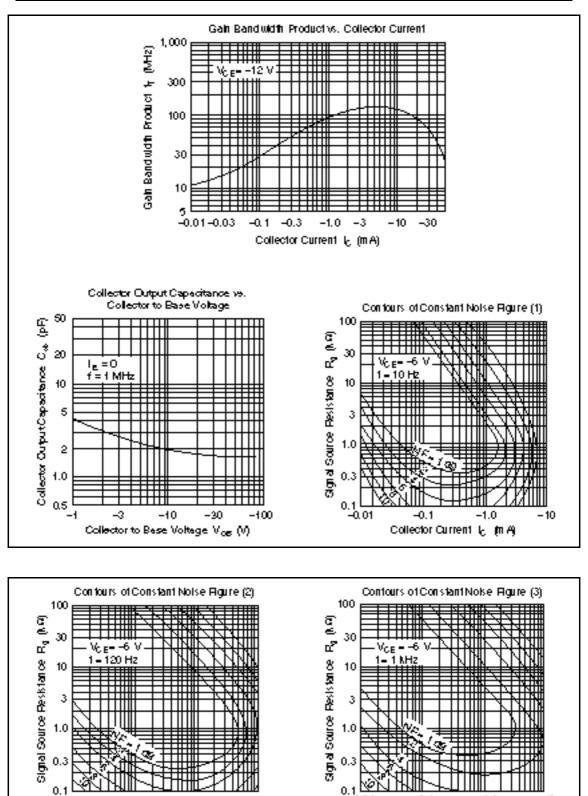
D

250 to 500 400 to 800

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-0.01

-0.1

Collector Currenti 🌜 (m A)

-1.0

- 10

-0.01

-0.1

Collector Current 🔓 (m A)

-1.0

- 10

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